













CSD17577Q3A

SLPS515A - AUGUST 2014-REVISED JANUARY 2016

CSD17577Q3A 30 V N-Channel NexFET™ Power MOSFET

Features

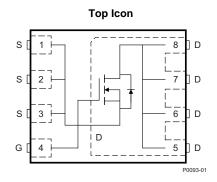
- Low Q_a and Q_{ad}
- Low Thermal Resistance
- Avalanche Rated
- Pb Free
- **RoHS Compliant**
- Halogen Free
- SON 3.3 mm × 3.3 mm Package

Applications

- Point-of-Load Synchronous Buck in Networking, Telecom, and Computing Systems
- Optimized for Control, and Sync FET Applications

Description

This 30 V, 4.0 m Ω , SON 3.3 mm × 3.3 mm NexFET™ power MOSFET is designed to minimize resistance in power conversion applications.



$R_{DS(on)}$ vs V_{GS} 20 $T_C = 25^{\circ}C, I_D = 16A$ $R_{DS(on)}$ - On-State Resistance $\,(m\Omega)\,$ 18 $T_C = 125^{\circ}C, I_D = 16A$ 16 14 12 10 8 6 2 0 10 12 V_{GS} - Gate-to- Source Voltage (V)

Product Summary

| $T_A = 25^\circ$ | С | TYPICAL VA | UNIT | | | | |
|---------------------|-------------------------------|-------------------------|------|----|--|--|--|
| V_{DS} | Drain-to-Source Voltage 30 | | | | | | |
| Q_g | Gate Charge Total (4.5 V) 12 | | | | | | |
| Q_{gd} | Gate Charge Gate-to-Drain | 2.5 | nC | | | | |
| D | Drain-to-Source On-Resistance | V _{GS} = 4.5 V | 5.3 | mΩ | | | |
| R _{DS(on)} | Diam-to-Source On-Resistance | V _{GS} = 10 V | 4.0 | mΩ | | | |
| $V_{GS(th)}$ | Threshold Voltage | 1.4 | | V | | | |

Ordering Information⁽¹⁾

| DEVICE | QTY | MEDIA | PACKAGE | SHIP |
|--------------|------|--------------|------------------|----------|
| CSD17577Q3A | 2500 | 13-Inch Reel | SON 3.3 x 3.3 mm | Tape and |
| CSD17577Q3AT | 250 | 7-Inch Reel | Plastic Package | Reel |

(1) For all available packages, see the orderable addendum at the end of the data sheet.

Absolute Maximum Ratings

| $T_{\Delta} = 2$ | 5°C | VALUE | UNIT |
|--------------------------------------|--|------------|-------|
| 'A - 2 | | TALUL | Oluli |
| V_{DS} | Drain-to-Source Voltage | 30 | V |
| V_{GS} | Gate-to-Source Voltage | ±20 | V |
| | Continuous Drain Current (Package limited) | 35 | |
| I _D | Continuous Drain Current (Silicon limited), T _C = 25°C | 83 | Α |
| | Continuous Drain Current (1) | 19 | |
| I_{DM} | Pulsed Drain Current (2) | 239 | Α |
| п | Power Dissipation ⁽¹⁾ | 2.5 | W |
| P_D | Power Dissipation, T _C = 25°C | 53 | VV |
| T _J , T _{stg} | Operating Junction Temperature, Storage Temperature | -55 to 150 | °C |
| E _{AS} | Avalanche Energy, single pulse $I_D = 28$ A, L = 0.1 mH, $R_G = 25$ Ω | 39 | mJ |

- (1) Typical $R_{\theta JA} = 50^{\circ} \text{C/W}$ on a 1 inch², 2 oz. Cu pad on a 0.06 inch thick FR4 PCB.
- (2) Max R_{θ,IC} = 3.0°C/W, pulse duration ≤100 μs, duty cycle ≤1%



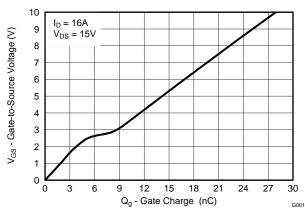




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4 Revision History

| C | changes from Original (August 2014) to Revision A | Page |
|---|---|------|
| • | Updated Power Dissipation value in Absolute Maximum Ratings table | 1 |
| • | Added Community Resources section | 7 |
| • | Updated Package Dimensions drawing | 8 |
| • | Updated PCB drawing. | 9 |
| • | Updated Stencil Pattern drawing | 5 |

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5 Specifications

5.1 Electrical Characteristics

 $(T_A = 25^{\circ}C \text{ unless otherwise stated})$

| | PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
|---------------------|----------------------------------|--|-----|------|------|------|
| STATIC | CHARACTERISTICS | | • | | ' | |
| BV _{DSS} | Drain-to-source voltage | V _{GS} = 0 V, I _D = 250 μA | 30 | | | V |
| I _{DSS} | Drain-to-source leakage current | V _{GS} = 0 V, V _{DS} = 24 V | | | 1 | μΑ |
| I _{GSS} | Gate-to-source leakage current | V _{DS} = 0 V, V _{GS} = 20 V | | | 100 | nA |
| V _{GS(th)} | Gate-to-source threshold voltage | $V_{DS} = V_{GS}$, $I_D = 250 \mu A$ | 1.1 | 1.4 | 1.8 | V |
| В | Drain to course an registeres | $V_{GS} = 4.5 \text{ V}, I_D = 10 \text{ A}$ | | 5.3 | 6.4 | mΩ |
| R _{DS(on)} | Drain-to-source on-resistance | V _{GS} = 10 V, I _D = 16 A | | 4.0 | 4.8 | mΩ |
| g _{fs} | Transconductance | V _{DS} = 15 V, I _D = 16 A | | 76 | | S |
| DYNAMI | C CHARACTERISTICS | | · | | , | |
| C _{iss} | Input capacitance | | | 1780 | 2310 | pF |
| C _{oss} | Output capacitance | $V_{GS} = 0 \text{ V}, V_{DS} = 15 \text{ V}, f = 1 \text{ MHz}$ | | 208 | 270 | pF |
| C _{rss} | Reverse transfer capacitance | | | 79 | 103 | рF |
| R_{G} | Series gate resistance | | | 1.4 | 2.8 | Ω |
| Qg | Gate charge total (4.5 V) | | | 13 | 17 | nC |
| Qg | Gate charge total (10 V) | | | 27 | 35 | nC |
| Q _{gd} | Gate charge gate-to-drain | V _{DS} = 15 V, I _D = 16 A | | 2.8 | | nC |
| Q _{gs} | Gate charge gate-to-source | | | 5.1 | | nC |
| Q _{g(th)} | Gate charge at V _{th} | | | 2.5 | | nC |
| Q _{oss} | Output charge | V _{DS} = 15 V, V _{GS} = 0 V | | 6 | | nC |
| t _{d(on)} | Turn on delay time | | | 4 | | ns |
| t _r | Rise time | V _{DS} = 15 V, V _{GS} = 10 V, | | 31 | | ns |
| t _{d(off)} | Turn off delay time | $I_{DS} = 16 \text{ A}, R_G = 0 \Omega$ | | 20 | | ns |
| t _f | Fall time | | | 4 | | ns |
| DIODE C | CHARACTERISTICS | | | | | |
| V _{SD} | Diode forward voltage | I _{SD} = 16 A, V _{GS} = 0 V | | 8.0 | 1 | V |
| Q _{rr} | Reverse recovery charge | V _{DS} = 15 V, I _F = 16 A, | | 8.2 | | nC |
| t _{rr} | Reverse recovery time | di/dt = 300 A/μs | | 8.6 | | ns |

5.2 Thermal Information

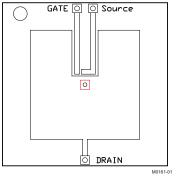
 $(T_A = 25^{\circ}C \text{ unless otherwise stated})$

| | THERMAL METRIC | MIN | TYP | MAX | UNIT |
|-----------------|--|-----|-----|-----|------|
| $R_{\theta JC}$ | Junction-to-case thermal resistance ⁽¹⁾ | | | 3.0 | °C/W |
| $R_{\theta JA}$ | Junction-to-ambient thermal resistance ⁽¹⁾⁽²⁾ | | | 55 | °C/W |

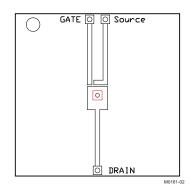
⁽¹⁾ R_{θJC} is determined with the device mounted on a 1 inch² (6.45 cm²), 2 oz. (0.071 mm thick) Cu pad on a 1.5 inches x 1.5 inches (3.81 cm x 3.81 cm), 0.06 inch (1.52 mm) thick FR4 PCB. R_{θJC} is specified by design, whereas R_{θJA} is determined by the user's board design.

(2) Device mounted on FR4 material with 1 inch2 (6.45 cm2), 2 oz. (0.071 mm thick) Cu.





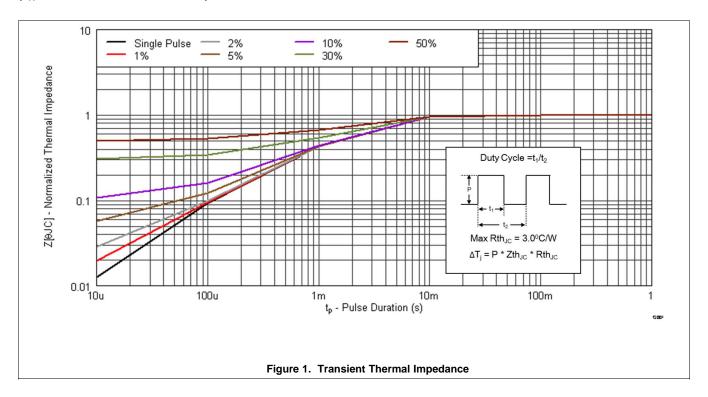
Max $R_{\theta JA} = 55^{\circ} C/W$ when mounted on 1 inch² (6.45 cm²) of 2 oz. (0.071 mm thick) Cu.



Max $R_{\theta JA} = 190^{\circ} C/W$ when mounted on a minimum pad area of 2 oz. (0.071 mm thick) Cu.

5.3 Typical MOSFET Characteristics

(T_A = 25°C unless otherwise stated)

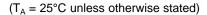


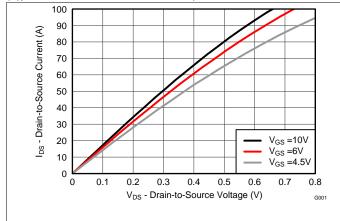
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Typical MOSFET Characteristics (continued)





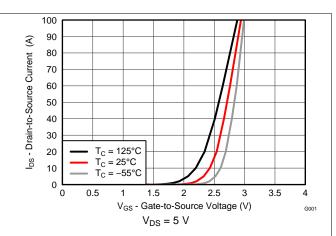
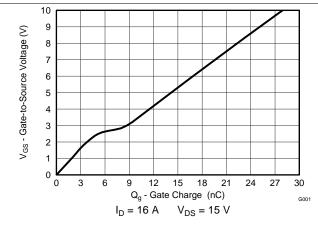


Figure 2. Saturation Characteristics





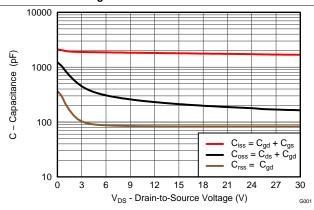


Figure 4. Gate Charge

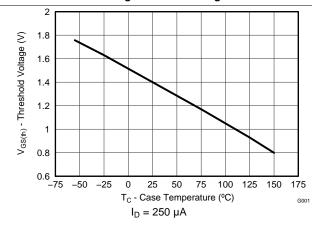


Figure 5. Capacitance

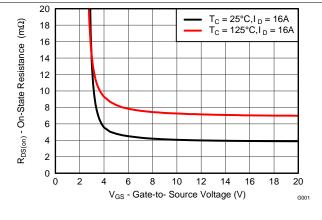


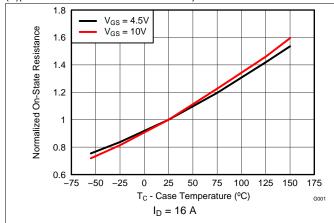
Figure 6. Threshold Voltage vs Temperature

Figure 7. On-State Resistance vs Gate-to-Source Voltage



Typical MOSFET Characteristics (continued)

 $(T_A = 25^{\circ}C \text{ unless otherwise stated})$



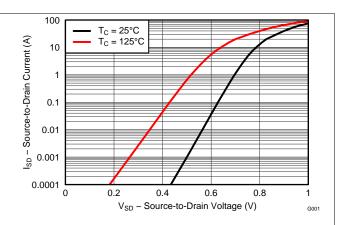
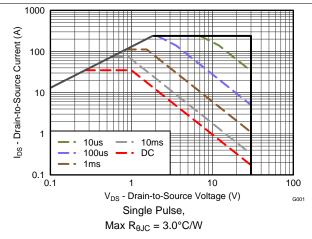


Figure 8. Normalized On-State Resistance vs Temperature





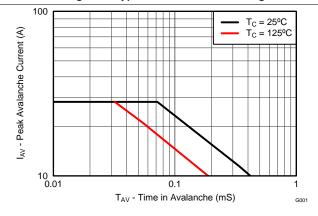


Figure 10. Maximum Safe Operating Area



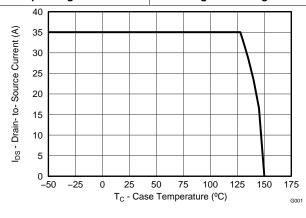


Figure 12. Maximum Drain Current vs Temperature



6 Device and Documentation Support

6.1 Community Resources

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

TI E2E™ Online Community TI's Engineer-to-Engineer (E2E) Community. Created to foster collaboration among engineers. At e2e.ti.com, you can ask questions, share knowledge, explore ideas and help solve problems with fellow engineers.

Design Support *TI's Design Support* Quickly find helpful E2E forums along with design support tools and contact information for technical support.

6.2 Trademarks

NexFET, E2E are trademarks of Texas Instruments.

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6.3 Electrostatic Discharge Caution



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

6.4 Glossary

SLYZ022 — TI Glossary.

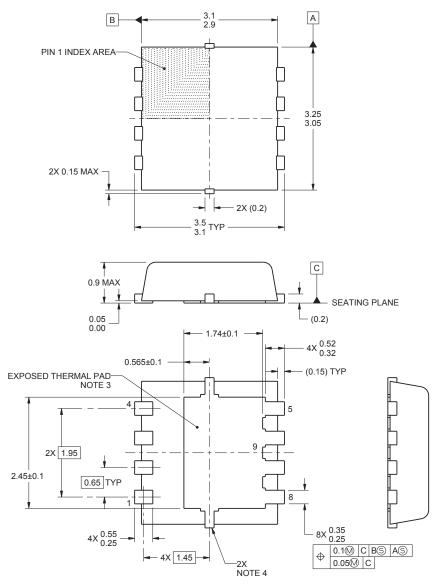
This glossary lists and explains terms, acronyms, and definitions.



7 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

7.1 Q3A Package Dimensions



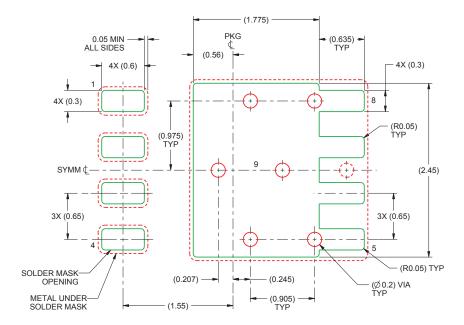
- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
- 2. This drawing is subject to change without notice.
- 3. The package thermal pad must be soldered to the printed circuit board for thermal and mechanical performance.
- 4. Metalized features are supplier options and may not be on the package.
- 5. All dimensions do not include mold flash or protrusions.

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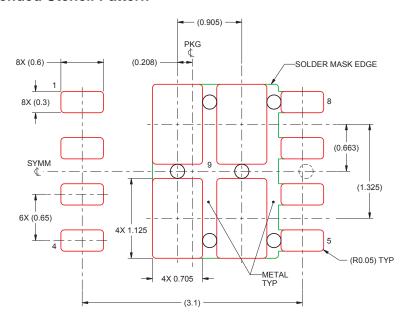
7.2 Q3A Recommended PCB Pattern



- This package is designed to be soldered to a thermal pad on the board. For more information, see QFN/SON PCB Attachment application report, SLUA271.
- Vias are optional depending on application, refer to device data sheet. If some or all are implemented, recommended via locations are shown.

For recommended circuit layout for PCB designs, see application note SLPA005 – Reducing Ringing Through PCB Layout Techniques.

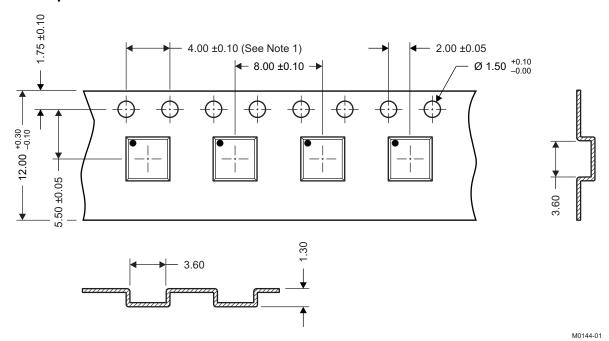
7.3 Q3A Recommended Stencil Pattern



1. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.



7.4 Q3A Tape and Reel Information



Notes: 1. 10-sprocket hole-pitch cumulative tolerance ±0.2

- 2. Camber not to exceed 1 mm in 100 mm, noncumulative over 250 mm
- 3. Material: black static-dissipative polystyrene
- 4. All dimensions are in mm, unless otherwise specified.
- 5. Thickness: $0.30 \pm 0.05 \text{ mm}$
- 6. MSL1 260°C (IR and convection) PbF-reflow compatible

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PACKAGE OPTION ADDENDUM

11-Jan-2016

PACKAGING INFORMATION

| Orderable Device | Status | Package Type | Package Drawing | Pins | Package Qty | Eco Plan | Lead/Ball Finish | MSL Peak Temp | Op Temp (°C) | Device Marking (4/5) | Samples |
|------------------|--------|--------------|--------------------|------|----------------|----------------------------|------------------|--------------------|--------------|----------------------|---------|
| CSD17577Q3A | ACTIVE | VSONP | DNH | 8 | 2500 | Green (RoHS & no Sb/Br) | CU SN | Level-1-260C-UNLIM | -40 to 85 | 17577 | Samples |
| CSD17577Q3AT | ACTIVE | VSONP | DNH | 8 | 250 | Green (RoHS & no Sb/Br) | CU SN | Level-1-260C-UNLIM | -40 to 85 | 17577 | Samples |

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead/Ball Finish Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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PACKAGE OPTION ADDENDUM

11-Jan-2016

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